

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3	(semiconductor near body) and (top near metal near interconnect) and (capacitor) and (bottom near electrode) and (capacitor near dielectric) and (top near electrode) and (protective near overcoat) and (cap).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:37
L2	8	(semiconductor near body) and (top near metal near interconnect) and (capacitor) and (bottom near electrode) and (capacitor near dielectric) and (top near electrode) and (protective near overcoat) and (cap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:37